# RF101 902–928 MHz RF Transmitter

## **Product Description**

The RF101 Transmitter IC is a fully integrated, monolithic device that utilizes the direct modulation technique. It includes a double-balanced mixer as the direct-conversion modulator and a logic-controlled power amplifier. The class A power amplifier is capable of delivering 100 mW (20 dBm) peak-envelope output power with the option of switching to 10 mW and 1 mW through two digital control signals.

The RF101 features low voltage operation (2.7 V to 5 V), offers low power consumption, and comes in a small, 32-pin TQFP plastic package.

The device is intended for spread-spectrum modulation schemes in the 900 MHz ISM band (902–928 MHz).

## **Applications**

- Direct Sequence Spread Spectrum Systems
- Frequency Hopping Spread Spectrum Systems
- Digital Cordless Telephones
- Wireless LANs
- · Wireless Modems
- Wireless Security
- Inventory Control Systems

#### **Features**

- Single-Chip Baseband-to-Antenna RF Transmitter.
- Double-Balanced Mixer for Baseband-to-RF Modulation.
- LO Input Buffer @ RF.
- On-chip 50 Ω matching on LO inputs.
- Linear RF Power Amplifier with 100 mW Peak Output Power.
- 30 dB gain.
- 20 dB Power Control Range using three digitally selectable Power Amplifiers for maximum efficiency.
- 3 Battery Cell operation (2.7 V to 5 V).
- 32-Pin TQFP package.

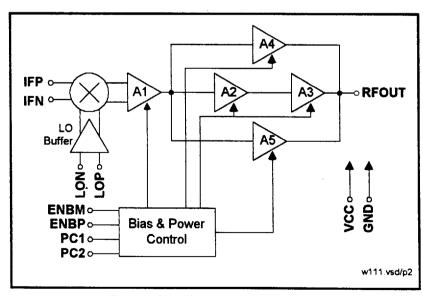


Figure 1. RF101 Transmitter Block Diagram

## **Technical Description**

The RF101 Transmitter block diagram, shown on the previous page, consists of two sections:

- 1. Baseband-to-RF Modulator
- Power Amp

#### Baseband-to-RF Modulator Section

Internally, the modulator consists of a double-balanced mixer and an output buffer, which drives the Power Amp input. The Modulator has two differential-input ports: the baseband (IFP, IFN) and the Local Oscillator (LO) inputs (LOP, LON). Even though the input ports are differential, they can be driven single-ended with no loss of gain. The typical IF input bandwidth is 50 MHz. The LO input can be driven with a 950 MHz (max.) signal that is as low as -10 dBm. The LO buffer can be biased up independently from the rest of the circuitry using the ENBM digital input.

### **Switchable Power Amplifiers Section**

The Power Amp can provide 100 mW peak-envelope output power (20 dBm), that may be reduced by 10 dB or 20 dB using the digital inputs PC1 and PC2. The power output is biased in linear mode such that the intermodulation spurious products are minimized. To reduce power consumption, the bias current is reduced when either the 10 dBm or 0 dBm power mode is selected. The whole transmitter (except the LO input buffer) can be shut down independently using the ENBP digital input.

#### Recommendations on Layout and Implementation

The LO inputs are internally biased, but external AC coupling capacitors of 47 pF are needed. Even though the LO input ports are differential, they can be driven single-ended. To use the LO single-ended, simply connect the LON port to a 47 pF cap to GND (see Figure 2 below).

Figure 2. Single-ended LO Input

 A 12K Ohm resistor to GND is recommended at pin 24, which provides the bias reference to the power amplifier. This provides the maximum output power from the power amplifier. Battery life may be extended at the expense of power output by increasing the bias reference resistor value up to 16K Ohms. Varying the bias reference resistor beyond the recommended range (12K to 16K) may result in improper operation of the power amplifier. Also, a change in the bias reference resistor may also require a change in the output matching network for optimum efficiency.

 As a general rule, the Vcc pins should have a proper bypassing circuit. A bypassing capacitor of 33 pF and a decoupling cap of 0.056 μF for low-frequency noise are recommended to all Vcc pins.

Special attention should be paid to Vcc pin 16. It is essential to keep the trace short to eliminate inductance. To ensure the proper operation of the PA, a bypassing cap of 12 pF to 22 pF from pin 16 to GND is required. However, due to layout variation, the value of the capacitor may vary. A longer trace which increases the inductance will require a smaller capacitor.

4. Proper heat-sinking may be required to prevent damage to the PA if it is operating close to maximum ratings. The maximum junction temperature allowed is 125°C for proper operation. The junction temperature is determined by the following equation:

$$T_i = T_A + \theta_{iA} \cdot P_{DC}$$

where: T<sub>j</sub> is the junction temperature, T<sub>A</sub> is the ambient temperature, θ<sub>jA</sub> is 90°C/W, and P<sub>DC</sub> is the DC power dissipation.

 The Power Amplifier output port requires a matching network for maximum power transfer (refer to Figure 3 below for an example of a matching circuit). However, the values are layout-sensitive. A longer trace will require a smaller capacitor.

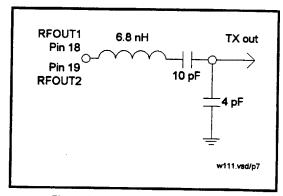


Figure 3. Typical PA Output Matching

## **Interface Description**

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The RF101 interface signal diagram is shown in Figure 5, and the corresponding interface signals are described by functional group in Table 1. The signal pinout diagram for the RF101 is shown in Figure 4.

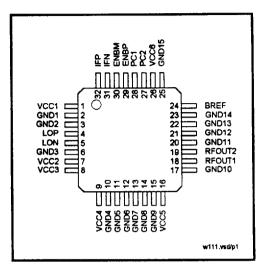


Figure 4. RF101 Pin Signals – 32-Pin TQFP

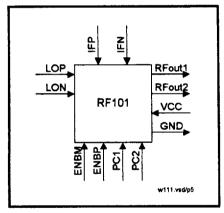


Figure 5. RF101 Signal Interface Diagram

Table 1. Pin Description

|                      | table t. Fill bescription        |  |  |  |  |  |  |  |
|----------------------|----------------------------------|--|--|--|--|--|--|--|
| Pin                  | Name                             | Description  |  |  |  |  |  |  |
| 1                    | VCC1                             | Reference power supply.  |  |  |  |  |  |  |
| 2                    | GND1                             | Reference ground.  |  |  |  |  |  |  |
| 3                    | GND2                             | Modulator ground.  |  |  |  |  |  |  |
| 4 5                  | LOP<br>LON                       | Modulator Differential LO input pins. Internally biased.  External AC coupling capacitors are needed.  |  |  |  |  |  |  |
| 6                    | GND3                             | Modulator ground.  |  |  |  |  |  |  |
| 7<br>8               | VCC2<br>VCC3                     | Modulator power supply.  |  |  |  |  |  |  |
| 9                    | VCC4                             | Modulator power supply for output buffer.  |  |  |  |  |  |  |
| 10<br>11<br>12<br>13 | GND4<br>GND5<br>GND6<br>GND7     | Power Amp driver ground.   |  |  |  |  |  |  |
| 14<br>15             | GND8<br>GND9                     | Power Amp output stage ground.   |  |  |  |  |  |  |
| 16                   | VCC5                             | Power Amp driver power supply.   |  |  |  |  |  |  |
| 17                   | GND10                            | Power Amp output stage ground.   |  |  |  |  |  |  |
| 18<br>19             | RFOUT1<br>RFOUT2                 | 1 · - · · · · · · · · · · · · · · · · ·  |  |  |  |  |  |  |
| 20<br>21<br>22<br>23 | GND11<br>GND12<br>GND13<br>GND14 | Power Amp output stage ground.   |  |  |  |  |  |  |
| 24                   | BREF                             | Bias Reference (a 12K Ohm resistor is recommended).  |  |  |  |  |  |  |
| 25                   | GND15                            | Power Amp bias control circuit ground.   |  |  |  |  |  |  |
| 26                   | VCC6                             | Power Amp bias control circuit power supply.   |  |  |  |  |  |  |
| 27<br>28             | PC2<br>PC1                       | Digital control input pins for selecting output power.   |  |  |  |  |  |  |
| 29                   | ENBP                             | Power down digital input for modulator and power amp.  |  |  |  |  |  |  |
| 30                   | ENBM                             | Power down for reference and LO input. Turns off whole chip.   |  |  |  |  |  |  |
| 31<br>32             | IFN<br>IFP                       | Modulator Differential IF input pins. Internally based.<br>External AC coupling capacitors are needed. |  |  |  |  |  |  |

# **Transmitter Specifications**

Electrical specifications are given below in Table 2. Absolute maximum ratings are given below in Table 3.

Table 2. Electrical Specifications\*

Test Conditions:  $T_A = 25$  °C,  $V_{CC} = 3.6$  V,  $f_{LO} = 915$  MHz,  $P_{LO} = -10$  dBm,  $f_{IF} = 200$  KHz,  $V_{IF} = 120$  mV<sub>PP</sub>,  $R_{BREF} = 12$ K Ohm

| Parameter                                 |  | Min | Тур                  | Max  | Units                    |
|---|--|-----|----------------------|------|--------------------------|
| Gain Variation vs. Frequency              | 902 MHz < f <sub>LO</sub> < 928 MHz                      |     | 0.5                  | 1.5  | dB                       |
| Peak-Envelope Output Power:               | PC1,2 = L,L<br>PC1,2 = L,H<br>PC1,2 = H,L<br>PC1,2 = H,H |     | 21<br>9<br>0<br>-30  |      | dBm<br>dBm<br>dBm<br>dBm |
| Total Supply Current:                     | PC1,2 = L,L<br>PC1,2 = L,H<br>PC1,2 = H,L<br>Standby     |     | 175<br>55<br>33<br>1 | ·    | mA<br>mA<br>mA<br>μA     |
| Modulator Supply Current                  |  |     | 20                   |      | mA                       |
| IM3:                                      | PC1,2 = L,L<br>PC1,2 = L,H<br>PC1,2 = H,L                |     | -18<br>-23<br>-23    |      | dBc                      |
| IP3                                       | PC1,2 = L,L  |     | 30                   |      | dBm                      |
| Output VSWR for Unconditional Stability   |  |     |                      | 10   |                          |
| LO Input Power Required                   |  | -13 | -10                  | 0    | dBm                      |
| LO Suppression                            |  |     | -25                  |      | dBc                      |
| LO Return Loss (902–928 MHz)              |  |     |                      | -9.5 | dB                       |
| LO-to-IF input Isolation @ 915 MHz        |  |     | 48                   |      | dB                       |
| RF Output-to-IF Input Isolation @ 915 MHz |  |     | 48                   |      | dB                       |
| RF Output-to-LO Isolation @ 915 MHz       |  |     | 55                   |      | dB                       |
| IF input impedance                        |  |     | 10                   |      | ΚΩ                       |
| IF Input Bandwidth                        |  |     | 50                   |      | MHz                      |
| LO Input Impedance                        |  |     | 50                   |      | Ω                        |
| Power Supply Range                        |  | 2.7 |                      | 5    | V                        |
| Operating Temperature Range               |  | -10 | 25                   | 70   | °C                       |

These measurements are taken with the recommended PA output matching and bypassing caps for VCC, as described in the Technical Description section.

Table 3. Absolute Maximum Ratings

| Parameter                     | Symbol           | Min | Max | Unit |
|-------------------------------|------------------|-----|-----|------|
| Storage Temperature           | T <sub>STG</sub> | -40 | 125 | *c   |
| Power Dissipation             | Po               | -   | 900 | mW   |
| Supply Voltage                | Vcc              | 0   | 5.5 | V    |
| Input Voltage Range           | _                | GND | VCC | V    |
| LO Input Power                | P <sub>LO</sub>  | _   | 5   | dBm  |
| IF Input Level (single-ended) | V <sub>IF</sub>  | _   | 500 | mV₂  |

#### **Module Dimensions**

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RF101 module dimensions are shown below in Figure 6.

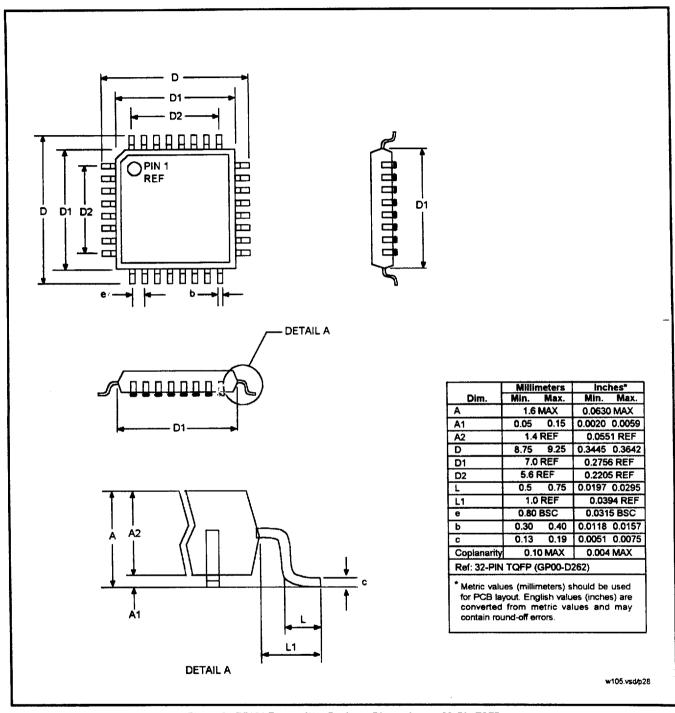


Figure 6. RF101 Transmitter Package Dimensions – 32-Pin TQFP

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